SiHF22N60E

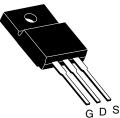


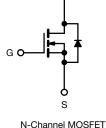


E Series Power MOSFET

PRODUCT SUMMA	RY	
V _{DS} (V) at T _J max.	650)
R _{DS(on)} max. (Ω) at 25 °C	$V_{GS} = 10 V$	0.18
Q _g max. (nC)	86	
Q _{gs} (nC)	11	
Q _{gd} (nC)	24	
Configuration	Sing	le

TO-220 FULLPAK





FEATURES

- Low figure-of-merit (FOM) Ron x Qa
- Low input capacitance (Ciss)
- · Reduced switching and conduction losses
- Ultra low gate charge (Q_q)
- Avalanche energy rated (UIS)
- · Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- · Server and telecom power supplies
- Switch mode power supplies (SMPS)
- Power factor correction power supplies (PFC)
- Lighting
 - High-intensity discharge (HID)
 - Fluorescent ballast lighting
- Industrial
 - Welding
 - Induction heating
 - Motor drives
 - Battery chargers
 - Renewable energy
 - Solar (PV inverters)

ORDERING INFORMATION	
Package	TO-220 FULLPAK
Lead (Pb)-free	SiHF22N60E-E3
Lead (Pb)-free and Halogen-free	SiHF22N60E-GE3

ABSOLUTE MAXIMUM RATINGS (T _C :	= 25 °C, unless otherwi	se noted)		
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V _{DS}	600	v
Gate-Source Voltage		V _{GS}	± 30	v
Continuous Drain Current (T. -150 °C) θ	$V_{GS} \text{ at 10 V} \qquad \frac{T_C = 25 \text{ °C}}{T_C = 100 \text{ °C}}$		21	
Continuous Drain Current (T _J = 150 °C) ^e	$T_{\rm C} = 100 ^{\circ}{\rm C}$	I _D	13	A
Pulsed Drain Current ^a	I _{DM}	56		
Linear Derating Factor			0.28	W/°C
Single Pulse Avalanche Energy ^b		E _{AS}	367	mJ
Maximum Power Dissipation		PD	35	W
Operating Junction and Storage Temperature Range	Э	T _J , T _{stg}	-55 to +150	°C
Drain-Source Voltage Slope	T _J = 125 °C	d\//dt	70	V/ns
Reverse Diode dV/dt ^d	dV/dt	11	v/ns	
Soldering Recommendations (Peak temperature) ^c	for 10 s		300	°C
Mounting Torque	M3 screw		0.6	Nm

Notes

a. Repetitive rating; pulse width limited by maximum junction temperature.

- b. V_{DD} = 50 V, starting T_J = 25 °C, L = 28.2 mH, R_g = 25 Ω , I_{AS} = 5.1 A.
- c. 1.6 mm from case.
- d. $I_{SD} \leq I_D$, dl/dt = 100 A/µs, starting T_J = 25 °C.
- e. Limited by maximum junction temperature.

S16-1084-Rev. J, 06-Jun-16

1 For technical questions, contact: hvm@vishay.com

THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com





INGS							
SYMBOL	TYP.		MAX.		UNIT		
R _{thJA}	-		65			°C ///	
R _{thJC}	-		3.6			-0/w	
unless otherwi	se noted)						
SYMBOL	TES	T CONDIT	IONS	MIN.	TYP.	MAX.	UNI
V _{DS}	V _{GS} =	= 0 V, I _D =	250 µA	600	-	-	V
$\Delta V_{DS}/T_{J}$	Reference	to 25 °C,	l _D = 250 μA	-	0.71	-	V/°(
V _{GS(th)}	V _{DS} =	$= V_{GS}, I_D =$	250 µA	2	-	4	V
		$V_{GS} = \pm 20$	V	-	-	± 100	nA
IGSS		$V_{GS} = \pm 30$	V	-	-	± 1	μA
	V _{DS} =	= 600 V, V _G	_{as} = 0 V	-	-	1	
DSS	V _{DS} = 480 V	/, V _{GS} = 0 \	√, T _J = 125 °C	-	-	10	μA
R _{DS(on)}	$V_{GS} = 10 V$			-	0.15	0.18	Ω
9 _{fs}	V _D s	_s = 8 V, I _D :	= 5 A	-	6.4	-	S
•	•						•
C _{iss}		$V_{cc} = 0.V$	1	-	1920	-	
C _{oss}	$V_{DS} = 100 V,$		-	90	-]	
		f = 1 MH:	Z	-	6	-	
C _{o(er)}			-	73	-	pF	
C _{o(tr)}	$V_{\rm DS} = 0.0$	7 to 480 V,	V _{GS} = 0 V	-	263	-	
Qq				-	57	86	
	V _{GS} = 10 V	I _D = 11	A, V _{DS} = 480 V	-	11	-	nC
				-	24	-	1
-				-	18	36	
t _r	- 	- 380 \/ I_	— 11 Δ	-	27	54	1
t _{d(off)}				-	66	99	ns
t _f	1			-	35	70	1
R _g	f = 1 MHz, open drain		0.3	0.77	1.2	Ω	
	• 						
۱ _S	MOSFET syml showing the	MOSFET symbol showing the integral reverse p - n junction diode		-	-	21	
I _{SM}	integral revers			-	-	56	A
V _{SD}	T _{.1} = 25 °C	C, I _S = 11 A	A, V _{GS} = 0 V	-	-	1.2	V
00	, <u>,</u>				<u> </u>		
trr				-	344	-	ns
t _{rr} Q _{rr}	T _J = 25	5 °C, I _F = I _s 100 A/µs, '	$_{S} = 11 \text{ A},$	-	344 5.3	-	ns µC
	RthJA RthJC SYMBOL VDS ΔVDs/TJ VGS(th) IGSS IDSS RDS(on) 9fs Ciss Coss Corrss Co(er) Co(er) Qg Qgd td(on) tr tf Rg ics Is Is	$\begin{tabular}{ c c c c } \hline R_{th,JA} & - & & \\ \hline R_{th,JC} & - & & \\ \hline \hline R_{th,JC} & - & & \\ \hline \hline & & & \\ \hline & & \\ \hline & & & \\ \hline \\ \hline$	$\begin{tabular}{ c c c c } \hline R_{thJC} & - & & & & & & & & & & & & & & & & & $	$\begin{tabular}{ c c c c } \hline R_{thJA} & - & 65 \\ \hline R_{thJC} & - & 3.6 \\ \hline \hline \\ \hline $	$\begin{tabular}{ c c c c c c } \hline R_{thJA} & - & 65 \\ \hline R_{thJC} & - & 3.6 \\ \hline $SYMBOL$ & TEST CONDITIONS$ & MIN. \\ \hline V_{DS} & $V_{GS} = 0 V, I_D = 250 \ \mu A$ & 600 \\ \hline $\Delta V_{DS}/T_J$ & Reference to 25 °C, I_D = 250 \ \mu A$ & - \\ \hline $V_{GS}(th)$ & $V_{DS} = V_{GS}, I_D = 250 \ \mu A$ & 2 \\ \hline $V_{GS}(th)$ & $V_{DS} = V_{GS}, I_D = 250 \ \mu A$ & 2 \\ \hline $V_{GS} = \pm 30 \ V$ & - \\ \hline $V_{DS} = 600 \ V, V_{GS} = 0 \ V$ & - \\ \hline $V_{DS} = 600 \ V, V_{GS} = 0 \ V$ & - \\ \hline $V_{DS} = 480 \ V, V_{GS} = 0 \ V$ & - \\ \hline $V_{DS} = 480 \ V, V_{GS} = 0 \ V$ & - \\ \hline $V_{DS} = 480 \ V, V_{GS} = 0 \ V$ & - \\ \hline $V_{DS} = 480 \ V, V_{GS} = 0 \ V$ & - \\ \hline $V_{DS} = 10 \ V$ & $I_D = 11 \ A$ & - \\ \hline $V_{DS} = 10 \ V$ & $I_D = 11 \ A$ & - \\ \hline $V_{DS} = 100 \ V$ & $I_D = 5 \ A$ & - \\ \hline \hline $V_{DS} = 100 \ V$ & $I_D = 100 \ V$ & $- \\ \hline C_{rss} & $V_{GS} = 10 \ V$ & $I_D = 11 \ A$ & - \\ \hline $V_{DS} = 0 \ V$ to 480 \ V, V_{GS} = 0 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 0 \ V$ to 480 \ V, V_{GS} = 0 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ & $I_D = 11 \ A$ & - \\ \hline $V_{DS} = 10 \ V$ & $I_D = 11 \ A$ & - \\ \hline $V_{DS} = 10 \ V$ \ V_{DS} = 0 \ V$ to 480 \ V, V_{GS} = 0 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ & $I_D = 11 \ A$ & - \\ \hline $V_{DS} = 10 \ V$ \ V_{DS} = 480 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ & $I_D = 11 \ A$ & $V_{DS} = 480 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ \ V_{DS} = 10 \ V$ \ V_{DS} = 480 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ \ V_{DS} = 11 \ A$ & $V_{DS} = 480 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ \ V_{DS} = 11 \ A$ & $V_{DS} = 480 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ \ V_{DS} = 11 \ A$ & $V_{DS} = 480 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ \ V_{DS} = 11 \ A$ & $V_{DS} = 480 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ \ V_{DS} = 11 \ A$ & $V_{DS} = 480 \ V$ & - \\ \hline $C_{o(tr)$ & $V_{DS} = 10 \ V$ \ V_{DS} = 11 \ A$ & $V_{DS} = 11 \ A$ & $V_{DS} = 10 \ V$ \ C_{O(tr)$ \ V_{DS} = 0 \ V$ \ C_{O(tr)$ \ V_{DS} =$	$\begin{tabular}{ c c c c c c } \hline $P_{th,JC}$ & - & 3.6 \\ \hline $P_{th,JC}$ & - & 3.6 \\ \hline $unless otherwise noted] \\ \hline $SYMBOL$ & $TEST CONDITIONS$ & MIN. TYP. \\ \hline V_{DS} & $V_{GS} = 0 V, I_D = 250 \ \mu A$ & 600 & -$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$$	$\begin{tabular}{ c c c c c c } \hline P_{th_JC} & - & 3.6 & \circCW$ \\ \hline P_{th_JC} & - & 3.6 & \circCW$ \\ \hline P_{th_JC} & - & 3.6 & \circCW$ \\ \hline P_{th_JC} & 1.5 & 0.18 & $V_{DS} = 480$ V, $V_{GS} = 0$ V & $-$ & $-$ & 10 & $V_{DS} = 480$ V, $V_{GS} = 0$ V & $-$ & $-$ & 10 & $V_{DS} = 480$ V, $V_{GS} = 0$ V & $-$ & $-$ & 10 & $V_{DS} = 480$ V, $V_{GS} = 0$ V & $-$ & $-$ & 10 & $P_{DS(on)}$ & $V_{GS} = 10$ V & $I_D = 11$ A$ & $-$ & 0.15 & 0.18 & g_{15} & $V_{DS} = 8$ V, $I_D = 5$ A$ & $-$ & 6.4 & $-$ & $-$ & 10 & $P_{DS(on)}$ & $V_{GS} = 10$ V, $g_{S} = 0$ V$ & $-$ & 11 & $-$ & 0.15 & 0.18 & $-$ & 6.4 & $-$ & $-$ & $-$ & 10 & $P_{DS(on)}$ & $V_{DS} = 8$ V, $I_D = 5$ A$ & $-$ & 6.4 & $-$ & $-$ & $-$ & 10 & $P_{DS} = 10$ V, $g_{S} = 10$ V, $g_{S} = 0$ V$ & $-$ & $-$ & 1220 & $-$ & $-$ & $-$ & 10 & $-$ & $-$ & $-$ & $-$ & 10 & $-$ & $-$ & $-$ & 10 & $-$ & $-$ & $-$ & $-$ & $-$ & 10 & $-$ & $-$ & $-$ & $-$ & $-$ & $-$ & 10 & $P_{DS} = 10$ V, $g_{S} = 10$ V, $g_{S} = 0$ V$ & $-$ & $

Notes

a. $C_{oss(er)}$ is a fixed capacitance that gives the same energy as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DSS} .

b. $C_{oss(tr)}$ is a fixed capacitance that gives the same charging time as C_{oss} while V_{DS} is rising from 0 % to 80 % V_{DSS} .

Document Number: 91471



TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

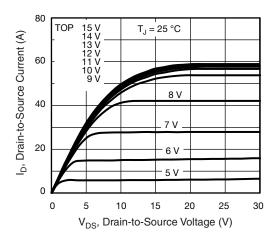


Fig. 1 - Typical Output Characteristics

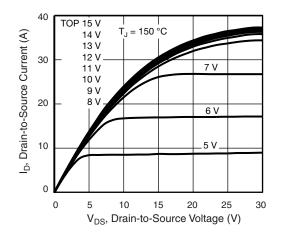


Fig. 2 - Typical Output Characteristics

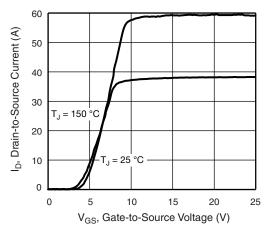


Fig. 3 - Typical Transfer Characteristics

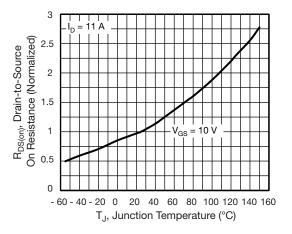


Fig. 4 - Normalized On-Resistance vs. Temperature

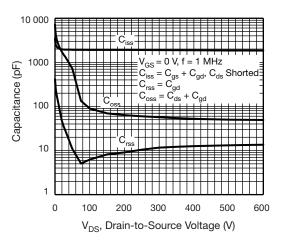


Fig. 5 - Typical Capacitance vs. Drain-to-Source Voltage

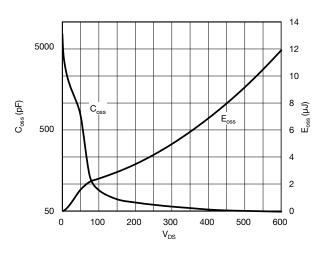


Fig. 6 - $C_{\rm oss}$ and $E_{\rm oss}$ vs. $V_{\rm DS}$

S16-1084-Rev. J, 06-Jun-16

3

Document Number: 91471

For technical questions, contact: <u>hvm@vishay.com</u>
THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT
ARE SUBJECT TO SPECIFI
Downloaded From Oneyac.com
Wvishay.com/doc?91000



SiHF22N60E

Vishay Siliconix

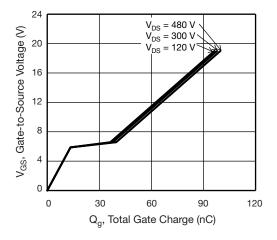


Fig. 7 - Typical Gate Charge vs. Gate-to-Source Voltage

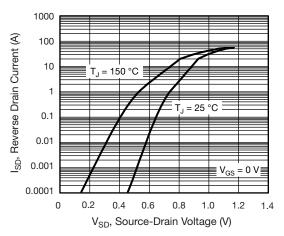


Fig. 8 - Typical Source-Drain Diode Forward Voltage

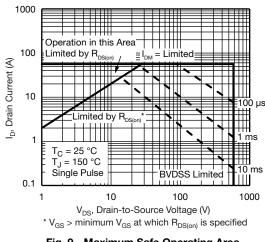


Fig. 9 - Maximum Safe Operating Area

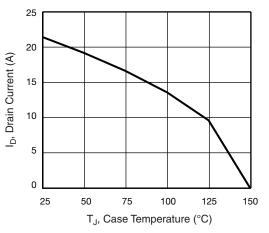


Fig. 10 - Maximum Drain Current vs. Case Temperature

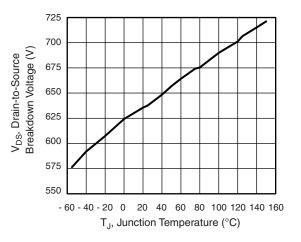
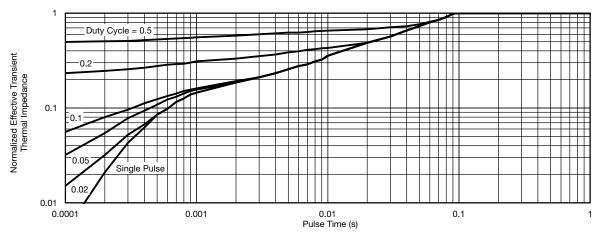


Fig. 11 - Temperature vs. Drain-to-Source Voltage

For technical questions, contact: hvm@vishay.com THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com



SiHF22N60E





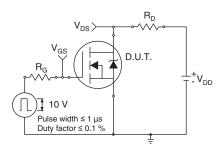


Fig. 13 - Switching Time Test Circuit

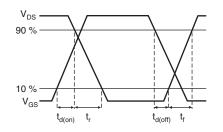


Fig. 14 - Switching Time Waveforms

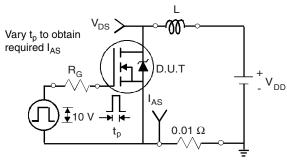


Fig. 15 - Unclamped Inductive Test Circuit

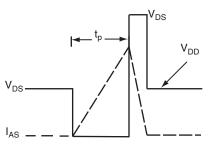


Fig. 16 - Unclamped Inductive Waveforms

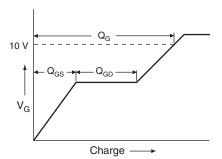


Fig. 17 - Basic Gate Charge Waveform

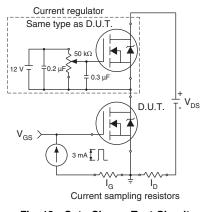


Fig. 18 - Gate Charge Test Circuit

S16-1084-Rev. J, 06-Jun-16

5 For technical questions, contact: <u>hvm@vishay.com</u> Document Number: 91471



Peak Diode Recovery dV/dt Test Circuit

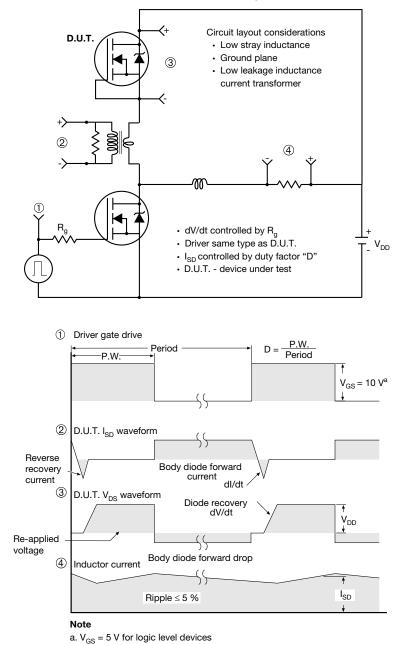


Fig. 19 - For N-Channel

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see www.vishay.com/ppg?91471.

S16-1084-Rev. J	, 06-Jun-16
-----------------	-------------

Document Number: 91471



TO-220 FULLPAK (High Voltage)

OPTION 1: FACILITY CODE = 9



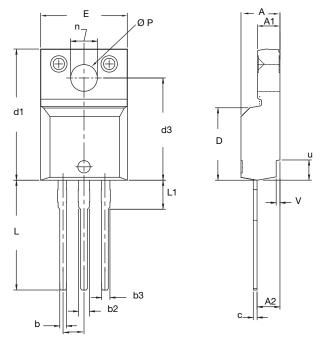
		MILLIMETERS	
DIM.	MIN.	NOM.	MAX.
A	4.60	4.70	4.80
b	0.70	0.80	0.91
b1	1.20	1.30	1.47
b2	1.10	1.20	1.30
С	0.45	0.50	0.63
D	15.80	15.87	15.97
е		2.54 BSC	
E	10.00	10.10	10.30
F	2.44	2.54	2.64
G	6.50	6.70	6.90
L	12.90	13.10	13.30
L1	3.13	3.23	3.33
Q	2.65	2.75	2.85
Q1	3.20	3.30	3.40
ØR	3.08	3.18	3.28

Notes

- 1. To be used only for process drawing
- 2. These dimensions apply to all TO-220 FULLPAK leadframe versions 3 leads
- 3. All critical dimensions should C meet $C_{pk} > 1.33$
- 4. All dimensions include burrs and plating thickness
- 5. No chipping or package damage
- Facility code will be the 1st character located at the 2nd row of the unit marking



OPTION 2: FACILITY CODE = Y



	MILLIN	MILLIMETERS		INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.		
А	4.570	4.830	0.180	0.190		
A1	2.570	2.830	0.101	0.111		
A2	2.510	2.850	0.099	0.112		
b	0.622	0.890	0.024	0.035		
b2	1.229	1.400	0.048	0.055		
b3	1.229	1.400	0.048	0.055		
С	0.440	0.629	0.017	0.025		
D	8.650	9.800	0.341	0.386		
d1	15.88	16.120	0.622	0.635		
d3	12.300	12.920	0.484	0.509		
E	10.360	10.630	0.408	0.419		
е	2.54	BSC	0.100) BSC		
L	13.200	13.730	0.520	0.541		
L1	3.100	3.500	0.122	0.138		
n	6.050	6.150	0.238	0.242		
ØP	3.050	3.450	0.120	0.136		
u	2.400	2.500	0.094	0.098		
V	0.400	0.500	0.016	0.020		

DWG: 5972

Notes

1. To be used only for process drawing

2. These dimensions apply to all TO-220 FULLPAK leadframe versions 3 leads

3. All critical dimensions should C meet $C_{pk} > 1.33$

4. All dimensions include burrs and plating thickness

5. No chipping or package damage
6. Facility code will be the 1st character located at the 2nd row of the unit marking

2

Document Number: 91359

For technical questions, contact: <u>hvmos.techsupport@vishay.com</u> THIS DOCUMENT IS SUBJECT TO CHANGE WITHOUT NOTICE. THE PRODUCTS DESCRIBED HEREIN AND THIS DOCUMENT ARE SUBJECT TO SPECIFI Downloaded From Oneyac.com



Vishay

Disclaimer

ALL PRODUCT, PRODUCT SPECIFICATIONS AND DATA ARE SUBJECT TO CHANGE WITHOUT NOTICE TO IMPROVE RELIABILITY, FUNCTION OR DESIGN OR OTHERWISE.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained in any datasheet or in any other disclosure relating to any product.

Vishay makes no warranty, representation or guarantee regarding the suitability of the products for any particular purpose or the continuing production of any product. To the maximum extent permitted by applicable law, Vishay disclaims (i) any and all liability arising out of the application or use of any product, (ii) any and all liability, including without limitation special, consequential or incidental damages, and (iii) any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.

Statements regarding the suitability of products for certain types of applications are based on Vishay's knowledge of typical requirements that are often placed on Vishay products in generic applications. Such statements are not binding statements about the suitability of products for a particular application. It is the customer's responsibility to validate that a particular product with the properties described in the product specification is suitable for use in a particular application. Parameters provided in datasheets and / or specifications may vary in different applications and performance may vary over time. All operating parameters, including typical parameters, must be validated for each customer application by the customer's technical experts. Product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein.

Except as expressly indicated in writing, Vishay products are not designed for use in medical, life-saving, or life-sustaining applications or for any other application in which the failure of the Vishay product could result in personal injury or death. Customers using or selling Vishay products not expressly indicated for use in such applications do so at their own risk. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay. Product names and markings noted herein may be trademarks of their respective owners.



单击下面可查看定价,库存,交付和生命周期等信息

>>Vishay(威世)

>>点击查看相关商品